

SKiiP® 2

6-pack - integrated intelligent Power System

Power section

SKiiP 342GD120-3DU

Power section features

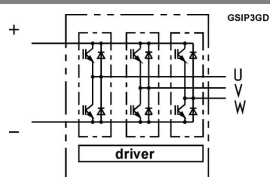
- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

1) with assembly of suitable MKP capacitor per terminal

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	Operating DC link voltage	1200	V
$V_{CC}^{1)}$		900	V
V_{GES}		± 20	V
I_C	$T_s = 25\text{ (70) °C}$	300 (225)	A
Inverse diode			
$I_F = -I_C$	$T_s = 25\text{ (70) °C}$	300 (225)	A
I_{FSM}	$T_j = 150\text{ °C}$, $t_p = 10\text{ ms}$; sin.	2160	A
I^2t (Diode)	Diode, $T_j = 150\text{ °C}$, 10 ms	23	kA²s
$T_j, (T_{stg})$	AC, 1 min. (mainterminals to heat sink)	- 40 (- 25) ... + 150 (125)	°C
V_{isol}		3000	V

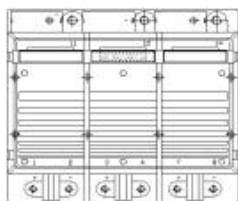
Characteristics		T _s = 25 °C unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
V _{CESat}	I _C = 250 A, T _j = 25 (125) °C		2,6 (3,1)	3,1	V
V _{CEO}	T _j = 25 (125) °C		1,2 (1,3)	1,5 (1,6)	V
r _{CE}	T _j = 25 (125) °C		5,3 (7)	6,3 (8,1)	mΩ
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES} , T _j = 25 (125) °C		(15)	0,4	mA
E _{on} + E _{off}	I _C = 250 A, V _{CC} = 600 V			75	mJ
	T _j = 125 °C, V _{CC} = 900 V			132	mJ
R _{CC' + EE'}	terminal chip, T _j = 125 °C		0,5		mΩ
L _{CE}	top, bottom		15		nH
C _{CHC}	per phase, AC-side		1,4		nF
Inverse diode					
V _F = V _{EC}	I _F = 250 A, T _j = 25 (125) °C		2,1 (2)	2,6	V
V _{TO}	T _j = 25 (125) °C		1,3 (1)	1,4 (1,1)	V
r _T	T _j = 25 (125) °C		3,3 (4)	4,5 (5,2)	mΩ
E _{rr}	I _C = 250 A, V _{CC} = 600 V			10	mJ
	T _j = 125 °C, V _{CC} = 900 V			12	mJ
Mechanical data					
M _{dc}	DC terminals, SI Units	6		8	Nm
M _{ac}	AC terminals, SI Units	13		15	Nm
w	SKiiP® 2 System w/o heat sink		2,7		kg
w	heat sink		6,6		kg

Thermal characteristics (P16 heat sink; 295 m³/h); "r" reference to temperature sensor					
$R_{th(j-s)I}$	per IGBT			0,09	K/W
$R_{th(j-s)D}$	per diode			0,25	K/W
$R_{th(s-a)}$	per module			0,036	K/W
Z_{th}	R_i (mK/W) (max. values)	$\tau_{th}(s)$			
	1 2 3 4	1	2	3	4
$Z_{th(j-r)I}$	10 69 11 0	1	0,13	0,001	1
$Z_{th(j-r)D}$	28 193 30 0	1	0,13	0,001	1
$Z_{th(r-a)}$	11,1 18,3 3,5 3,1	204	60	6	0,02



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* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



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6-pack - integrated intelligent Power System

6-pack
integrated gate driver

SKiiP 342GD120-3DU

Gate driver features

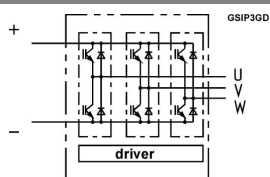
- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformer
- IEC 60068-1 (climate) 25/85/56

Absolute Maximum Ratings		$T_a = 25\text{ °C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
V_{S1}	stabilized 15 V power supply	18	V
V_{S2}	unstabilized 24 V power supply	30	V
V_{iH}	input signal voltage (high)	$15 + 0,3$	V
dv/dt	secondary to primary side	75	kV/ μ s
V_{isolIO}	input / output (AC, r.m.s., 2s)	3000	Vac
V_{isol12}	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
f_{sw}	switching frequency	20	kHz
f_{out}	output frequency for $I = I_C$; sin.	1	kHz
$T_{op} (T_{stg})$	operating / storage temperature	$-40 \dots +85$	°C

Characteristics		(T _a = 25 °C)			
Symbol	Conditions	min.	typ.	max.	Units
V _{S1}	supply voltage stabilized	14,4	15	15,6	V
V _{S2}	supply voltage non stabilized	20	24	30	V
I _{S1}	V _{S1} = 15 V	410+550*f/f _{max} +3,6*(I _{AC} /A)			mA
I _{S2}	V _{S2} = 24 V	300+390*f/f _{max} +2,6*(I _{AC} /A)			mA
V _{IT+}	input threshold voltage (High)	12,3			V
V _{IT-}	input threshold voltage (Low)	4,6			V
R _{IN}	input resistance	10			kΩ
t _{d(on)IO}	input-output turn-on propagation time	1,5			μs
t _{d(off)IO}	input-output turn-off propagation time	1,4			μs
t _{pERRRESET}	error memory reset time	9			μs
t _{TD}	top / bottom switch : interlock time	2,3			μs
I _{analogOUT}	8 V corresponds to max. current of 15 V supply voltage	300			A
I _{Vs1outmax}	(available when supplied with 24 V)	50			mA
I _{A0max}	output current at pin 13/20/22/24/26	5			mA
V _{0l}	logic low output voltage	0,6			V
V _{0H}	logic high output voltage	30			V
I _{TRIPSC}	over current trip level (I _{analog OUT} = 10 V)	375			A
I _{TRIPLG}	ground fault protection	87			A
T _{tp}	over temperature protection	110	120		°C
U _{DCTRIP}	trip level of U _{DC} -protection (U _{analog OUT} = 9 V); (option)	900			V

For electrical and thermal design support please use SEMISEL.
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